

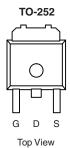
# 25N06L-TN3-VB Datasheet N-Channel 6 0-V (D-S) MOSFET

| PRODUCT SUMMARY     |                                  |                                 |  |  |
|---------------------|----------------------------------|---------------------------------|--|--|
| V <sub>DS</sub> (V) | $r_{DS(on)}\left(\Omega\right)$  | I <sub>D</sub> (A) <sup>a</sup> |  |  |
| 60                  | 0.026 at V <sub>GS</sub> = 10 V  | 45                              |  |  |
|                     | 0.029 at V <sub>GS</sub> = 4.5 V | 40                              |  |  |

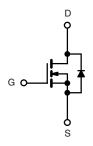
#### **FEATURES**

- Trench Power MOSFET
- 175 °C Junction Temperature





Drain Connected to Tab



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS $T_C =$                                | 25 °C, unless othe      | rwise noted                       |                |      |  |
|---|-------------------------|-----------------------------------|----------------|------|--|
| Parameter   |                         | Symbol                            | Limit          | Unit |  |
| Gate-Source Voltage   |                         | V <sub>GS</sub>                   | ± 20           | V    |  |
| Continuous Dunin Commant (T., 175 °C)b                          | T <sub>C</sub> = 25 °C  | - I <sub>D</sub>                  | 40             |      |  |
| Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>b</sup> | T <sub>C</sub> = 100 °C |                                   | 35             |      |  |
| Pulsed Drain Current  |                         | I <sub>DM</sub>                   | 100            | А    |  |
| Continuous Source Current (Diode Conduction)                    |                         | I <sub>S</sub>                    | 23             |      |  |
| Avalanche Current   |                         | I <sub>AS</sub>                   | 20             |      |  |
| Single Avalanche Energy (Duty Cycle ≤ 1 %)                      | L = 0.1 mH              | E <sub>AS</sub>                   | 20             | mJ   |  |
| Manifestory Brown Birelineting                                  | T <sub>C</sub> = 25 °C  | В                                 | 100            | 10/  |  |
| Maximum Power Dissipation                                       | T <sub>A</sub> = 25 °C  | P <sub>D</sub>                    | 3 <sup>a</sup> | W    |  |
| Operating Junction and Storage Temperature Range                | •                       | T <sub>J</sub> , T <sub>stg</sub> | - 55 to 175    | °C   |  |

| THERMAL RESISTANCE RATINGS               |              |                   |         |         |      |
|--|--------------|-------------------|---------|---------|------|
| Parameter                                |              | Symbol            | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient <sup>a</sup> | t ≤ 10 sec   | R <sub>thJA</sub> | 18      | 22      | °C/W |
| Maximum Junction-to-Ambient              | Steady State |                   | 40      | 50      |      |
| Maximum Junction-to-Case                 |              | R <sub>thJC</sub> | 3.2     | 4       |      |

#### Notes:

a. Surface Mounted on 1" x 1" FR4 board,  $t \le 10$  sec.

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|                     |   |   | _   |   |  |  |
|---------------------|---|---|---|---|--|--|
| Symbol              | Test Conditions   | Min   | Typ <sup>a</sup>  | Max   | Unit   |  |
| T                   |   |   | 1   | ı   |  |  |
|                     | 40 / D 1  | 60  |   |   | V  |  |
| V <sub>GS(th)</sub> |   | 1.0   | 2.0   | 3.0   | V  |  |
| I <sub>GSS</sub>    |   |   |   | ± 100   | nA   |  |
|                     | 20 60   |   |   | 1   |  |  |
| I <sub>DSS</sub>    |   |   |   | 50  | μΑ   |  |
|                     | $V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$   |   |   | 250   |  |  |
| I <sub>D(on)</sub>  | $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$   | 50  |   |   | Α  |  |
|                     | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A   |   | 0.026   |   | Ω  |  |
| r                   | $V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}, T_J = 125 ^{\circ}\text{C}$   |   | 0.055   |   |  |  |
| DS(on)              | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A, T <sub>J</sub> = 175 °C  |   | 0.069   |   |  |  |
|                     | $V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$  |   | 0.029   |   |  |  |
| 9 <sub>fs</sub>     | V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A   |   | 20  |   | S  |  |
|                     |   |   |   |   |  |  |
| C <sub>iss</sub>    |   |   | 1850  |   | pF   |  |
| C <sub>oss</sub>    | $V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$  |   | 140   |   |  |  |
| C <sub>rss</sub>    |   |   | 60  |   |  |  |
| $Q_g$               |   |   | 11  | 17  | nC   |  |
| $Q_{gs}$            | $V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}$  |   | 3   |   |  |  |
| $Q_{gd}$            |   |   | 3   |   |  |  |
| t <sub>d(on)</sub>  |   |   | 8   | 15  |  |  |
| t <sub>r</sub>      | $V_{DD}$ = 30 V, $R_L$ = 1.3 $\Omega$   |   | 15  | 25  | ns   |  |
| t <sub>d(off)</sub> | $I_D \cong 23 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$  |   | 30  | 45  |  |  |
| t <sub>f</sub>      |   |   | 25  | 40  |  |  |
| racteristics        | (T <sub>C</sub> = 25 °C)  |   | •   |   |  |  |
| I <sub>SM</sub>     |   |   |   | 50  | Α  |  |
| $V_{SD}$            | I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0 V  |   | 1.0   | 1.5   | V  |  |
| t <sub>rr</sub>     | I <sub>F</sub> = 15 A, di/dt = 100 A/μs   |   | 30  | 60  | ns   |  |
|                     | $I_{DSS}$ $I_{D(on)}$ $I_{D(on)}$ $I_{DS(on)}$ $I_{DS(on)}$ $I_{SS}$ $I_{SS}$ $I_{SS}$ $I_{SS}$ $I_{SS}$ $I_{SS}$ $I_{SS}$ $I_{SM}$ $I_{SM}$ $I_{SD}$ | $\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline \hline C_{iss} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} \\ \hline \hline C_{rss} & V_{GS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline \hline Q_{g} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline Q_{gd} & t_{d(on)} & t_r & V_{DD} = 30 \text{ V, } R_L = 1.3 \Omega \\ \hline t_{f} & I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega \\ \hline \hline \text{aracteristics} & (T_C = 25 \text{ °C}) \\ \hline \hline I_{SM} & V_{SD} & I_F = 15 \text{ A, } V_{GS} = 0 \text{ V} \\ \hline \end{array}$ | $\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 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A, } V_{GS} = 0 \text{ V} \\ \hline \end{array}$ | $\begin{array}{ c c c c }\hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 & 2.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 125 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{DS} = 15 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\\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} & 0.069 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} & 0.029 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 15 \text{ A} & 20 & \\ \hline \hline \\ \hline C_{ISS} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} & 140 & \\ \hline \hline C_{TSS} & 60 & \\ \hline Q_g & 11 & 17 & \\ \hline Q_{gS} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline Q_{gd} & 3 & 11 & 17 & \\ \hline V_{DD} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega & 30 & 45 & \\ \hline I_f & 25 \text{ 40} & \\ \hline \\ \text{aracteristics} & (T_C = 25 \text{ °C}) & \\ \hline \\ \hline \\ \hline \\ \hline \end{array}$ |  |

#### Notes:

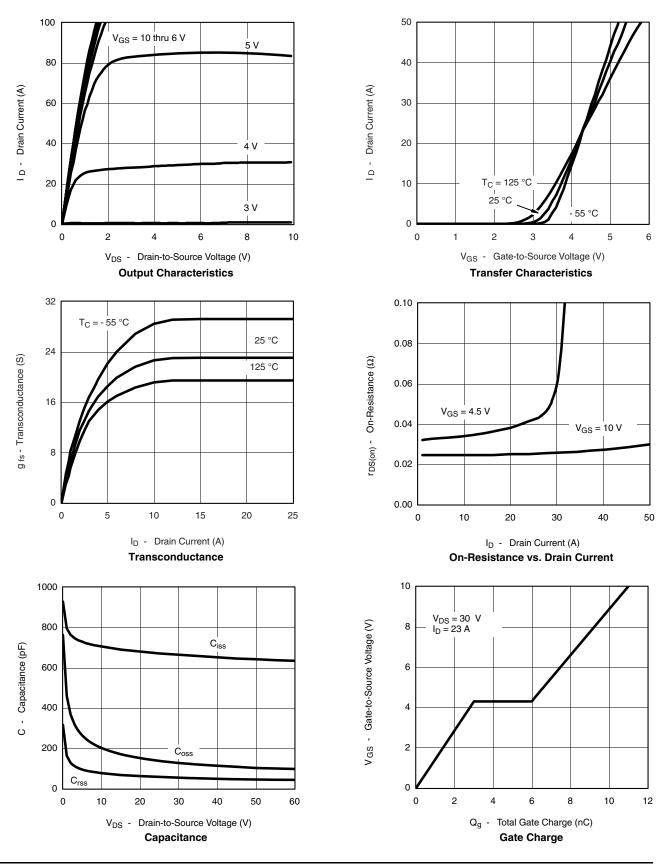
- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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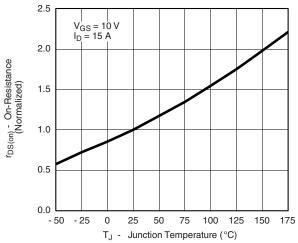


#### TYPICAL CHARACTERISTICS 25 °C unless noted

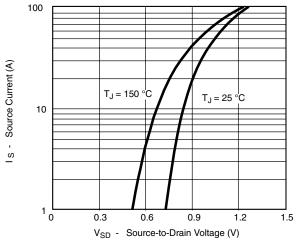




### TYPICAL CHARACTERISTICS 25 °C unless noted



On-Resistance vs. Junction Temperature

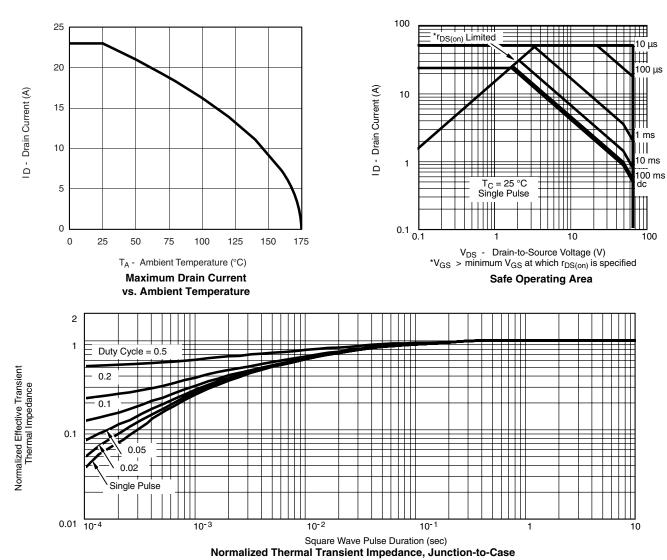


Source-Drain Diode Forward Voltage

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#### **THERMAL RATINGS**



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